ART1K6FH; ART1K6FHS; ART1K6FHG Power LDMOS transistor Rev. 3 — 8 July 2022 Proc

AMPLEON

Product data sheet

Product profile

1.1 General description

Based on Advanced Rugged Technology (ART), this 1600 W LDMOS RF power transistor has been designed to cover a wide range of applications for ISM, broadcast and communications. The unmatched transistor has a frequency range of 1 MHz to 425 MHz.

Table 1. **Application information**

Test signal	f	V _{DS}	PL	Gp	ησ
	(MHz)	(V)	(W)	(dB)	(%)
CW pulsed [1]	108	50	1400	28.7	77.3
CW pulsed [1]	108	55	1600	29.5	76.0
CW pulsed [2]	352	50	1200	20.0	68.0

^[1] Production circuit: $t_p = 100 \mu s$; $\delta = 10 \%$.

1.2 Features and benefits

- High breakdown voltage enables class E operation at V_{DS} = 48 V
- Suitable for V_{DS} = 50 and 55 V
- Qualified up to a maximum of V_{DS} = 55 V
- Characterized from 30 V to 55 V for extended power range
- Easy power control
- Integrated dual sided ESD protection enables class C operation and complete switch off of the transistor
- Excellent ruggedness with no device degradation
- High efficiency
- Excellent thermal stability
- Designed for broadband operation
- For RoHS compliance see the product details on the Ampleon website

^[2] Application circuit: $t_p = 100 \mu s$; $\delta = 10 \%$.

1.3 Applications

- Industrial, scientific and medical applications
 - Plasma generators
 - MRI systems
 - ◆ CO₂ lasers
 - ◆ Particle accelerators
- Broadcast
 - ◆ FM radio
 - ◆ VHF TV
- Communications
 - ♦ Non cellular communications
 - ◆ UHF radar

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
ART1K6FH (S	SOT539AN)		
1	drain1		1
2	drain2	1 2	
3	gate1	5	3 - 5
4	gate2	3 4	4 —
5	source [1]		
			2 sym117
ART1K6FHS	(SOT539BN)		
1	drain1		1
2	drain2	1 2	
3	gate1	5	3—
4	gate2	3 4	4 — 5
5	source [1]		
			2 sym117
ART1K6FHG	(SOT1248C)		
1	drain1		1
2	drain2	1 2	
3	gate1	5	3—
4	gate2	3 4	4 — 5
5	source [1]		
			2 sym117

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Package name	Orderable part number	12NC	3	Min. orderable quantity (pieces)
SOT539AN	ART1K6FHU	9349 603 27122	Tray; 20-fold; non-dry pack	60
SOT539BN	ART1K6FHSU	9349 605 33112	Tray; 20-fold; non-dry pack	60
SOT1248C	ART1K6FHGJ	9349 605 34118	TR13; 100-fold; 56 mm; non-dry pack	100

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	177	V
V_{GS}	gate-source voltage		-9	+13	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

5. Thermal characteristics

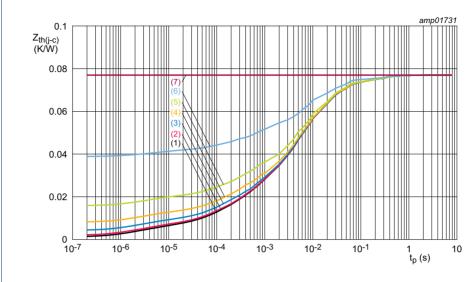
Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	$T_j = 95 ^{\circ}C$ [1][2]	0.077	K/W
Z _{th(j-c)}	transient thermal impedance from junction to case	$T_j = 95 \text{ °C}; t_p = 100 \mu\text{s}; \\ \delta = 10 \%$	0.018	K/W

^[1] T_j is the junction temperature.

^[2] R_{th(j-c)} is measured under RF conditions.

^[3] See Figure 1.



- (1) $\delta = 1 \%$
- (2) $\delta = 2 \%$
- (3) $\delta = 5 \%$
- (4) $\delta = 10 \%$
- (5) $\delta = 20 \%$
- (6) $\delta = 50 \%$
- (7) $\delta = 100 \% (DC)$

Fig 1. Transient thermal impedance from junction to case as a function of pulse duration

6. Characteristics

Table 6. DC characteristics

 $T_i = 25$ °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 5.5 \text{ mA}$	177	191	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 20 \text{ V}; I_D = 550 \text{ mA}$	1.5	2.1	2.5	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 50 V	-	-	2.8	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 20 \text{ V}$	-	81	-	А
I _{GSS}	gate leakage current	V _{GS} = 13 V; V _{DS} = 0 V	-	-	280	nA
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 19.25 \text{ A}$	-	0.084	-	Ω

Table 7. AC characteristics

 $T_i = 25$ °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{rs}	feedback capacitance	V _{GS} = 0 V; f = 1 MHz				
		V _{DS} = 50 V	-	1.71	-	pF
		V _{DS} = 55 V	-	1.65	-	pF
C _{iss}	input capacitance	V _{GS} = 0 V; f = 1 MHz				
		V _{DS} = 50 V	-	620	-	pF
		V _{DS} = 55 V	-	620	-	pF
C _{oss}	output capacitance	$V_{GS} = 0 V$; $f = 1 MHz$				
		V _{DS} = 50 V	-	193	-	pF
		V _{DS} = 55 V	-	185	-	pF

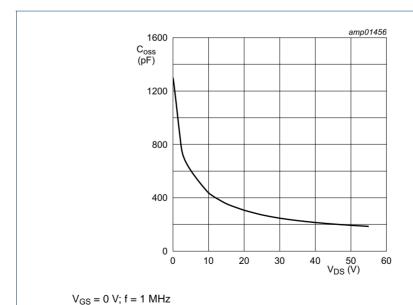


Fig 2. Output capacitance as a function of drain-source voltage; typical values per section

Table 8. RF characteristics

Test signal: pulsed RF; t_p = 100 μ s; δ = 5 %; f = 108 MHz; RF performance at V_{DS} = 55 V; I_{Dq} = 50 mA per section; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P _L = 1600 W	27	28.0	-	dB
RLin	input return loss	P _L = 1600 W	-	-16	-	dB
η_{D}	drain efficiency	P _L = 1600 W	71	74	-	%

7. Test information

7.1 Ruggedness in class-AB operation

The ART1K6FH, ART1K6FHS and ART1K6FHG are capable of withstanding a load mismatch corresponding to VSWR ≥ 65 : 1 through all phases under the following conditions: P_L = 1400 W pulsed at V_{DS} = 50 V and P_L = 1600 W pulsed at V_{DS} = 55 V; I_{Dq} = 100 mA per section; t_p = 100 $\mu s; \, \delta$ = 10 %; f = 108 MHz.

7.2 Impedance information

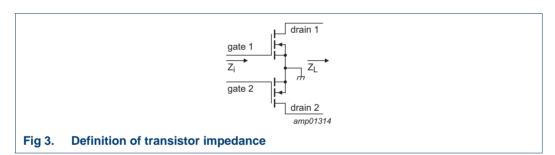


Table 9. Typical push-pull impedance

Simulated Z_i and Z_L device impedance.

f	Zi	Z _L	PL
(MHz)	(Ω)	(Ω)	(W)
$V_{DS} = 50 \text{ V}$			
108	2.4 – j8.7	3.3 + j0.7	1400
V _{DS} = 55 V			
108	2.4 – j8.7	3.5 + j0.8	1600

7.3 Test circuit

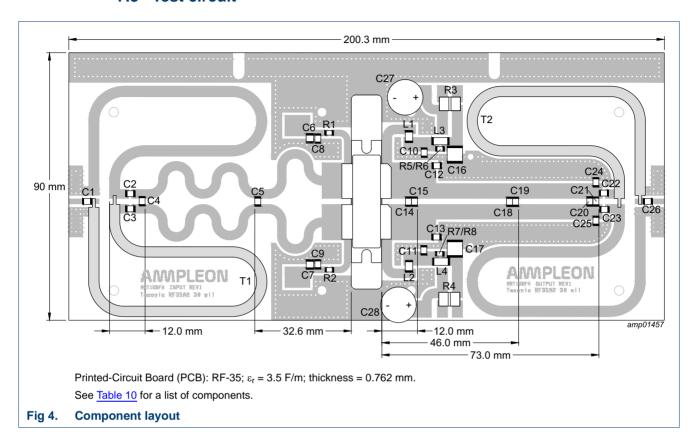


Table 10. List of components

For test circuit see Figure 4.

Component	Description	Value		Remarks
C1, C26	multilayer ceramic chip capacitor	470 pF	[1]	
C2, C3	multilayer ceramic chip capacitor	68 pF	[1]	
C4	multilayer ceramic chip capacitor	43 pF	[1]	
C5	multilayer ceramic chip capacitor	240 pF	[1]	
C6, C7	multilayer ceramic chip capacitor	4.7 μF, 50 V		Murata: GRM32ER71H475KA88L
C8, C9, C10, C11	multilayer ceramic chip capacitor	820 pF	[1]	
C12, C13	multilayer ceramic chip capacitor	180 pF	[1]	
C14, C15	multilayer ceramic chip capacitor	39 pF	[1]	
C16, C17	multilayer ceramic chip capacitor	4.7 μF, 100 V		TDK: C5750X7R2A475KT/A
C18, C19	multilayer ceramic chip capacitor	56 pF	[1]	
C20, C21	multilayer ceramic chip capacitor	51 pF	[1]	
C22, C23	multilayer ceramic chip capacitor	120 pF	[1]	
C24, C25	multilayer ceramic chip capacitor	20 pF	[1]	
C27, C28	electrolytic capacitor	2200 μF, 100 V		
L1, L2	air inductor	47 nH		Coilcraft: 1515SQ-47N
L3, L4	air inductor	82 nH		Coilcraft: 1515SQ-82N
R1, R2	resistor	4.7 kΩ		SMD 1206

ART1K6FH_1K6FHS_1K6FHG

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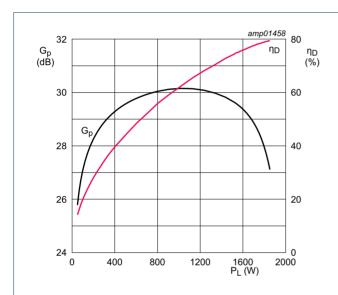
Table 10. List of components ...continued

For test circuit see Figure 4.

Component	Description	Value	Remarks
R3, R4	resistor	0.01 Ω	Vishay: WSHP2818
R5, R6, R7, R8	resistor	9.1 Ω	SMD 1206
T1, T2	semi rigid coax	50 Ω, 160 mm	EZ141-AL-TP/M17

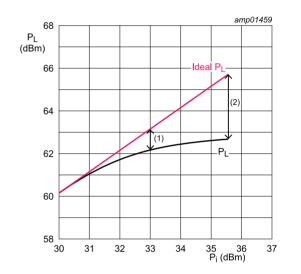
[1] American Technical Ceramics type 100B or capacitor of same quality.

7.4 Graphical data



 V_{DS} = 55 V; I_{Dq} = 100 mA per section; f = 108 MHz; t_p = 100 $\mu s;~\delta$ = 10 %.

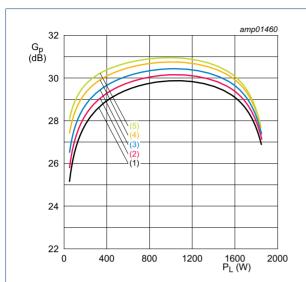
Fig 5. Power gain and drain efficiency as function of output power; typical values



 V_{DS} = 55 V; I_{Dq} = 100 mA per section; f = 108 MHz; t_p = 100 $\mu s;$ δ = 10 %.

- (1) $P_{L(1dB)} = 62.17 \text{ dBm } (1650 \text{ W})$
- (2) $P_{L(3dB)} = 62.67 \text{ dBm } (1850 \text{ W})$

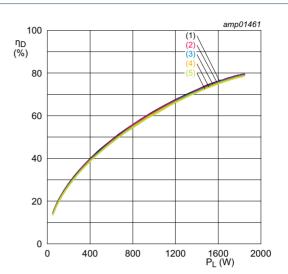
Fig 6. Output power as a function of input power; typical values



 $V_{DS} = 55 \text{ V; } f = 108 \text{ MHz; } t_p = 100 \text{ } \mu\text{s; } \delta = 10 \text{ } \%.$

- (1) $I_{Dq} = 50 \text{ mA per section}$
- (2) $I_{Da} = 100 \text{ mA per section}$
- (3) $I_{Dq} = 200 \text{ mA per section}$
- (4) $I_{Dq} = 400 \text{ mA per section}$
- (5) $I_{Dq} = 600 \text{ mA per section}$

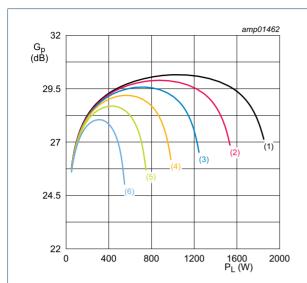
Fig 7. Power gain as a function of output power; typical values



 V_{DS} = 55 V; f = 108 MHz; t_p = 100 μ s; δ = 10 %.

- (1) $I_{Dq} = 50 \text{ mA per section}$
- (2) $I_{Dq} = 100 \text{ mA per section}$
- (3) $I_{Dq} = 200 \text{ mA per section}$
- (4) $I_{Dq} = 400 \text{ mA per section}$
- (5) $I_{Dq} = 600 \text{ mA per section}$

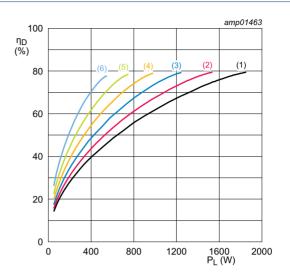
Fig 8. Drain efficiency as a function of output power; typical values



 I_{Dq} = 100 mA per section; f = 108 MHz; t_p = 100 $\mu s;$ δ = 10 %.

- (1) $V_{DS} = 55 \text{ V}$
- (2) $V_{DS} = 50 \text{ V}$
- (3) $V_{DS} = 45 \text{ V}$
- (4) $V_{DS} = 40 \text{ V}$
- (5) $V_{DS} = 35 \text{ V}$
- (6) $V_{DS} = 30 \text{ V}$

Fig 9. Power gain as a function of output power; typical values



 I_{Dq} = 100 mA per section; f = 108 MHz; t_p = 100 $\mu s;$ δ = 10 %.

- (1) $V_{DS} = 55 \text{ V}$
- (2) $V_{DS} = 50 \text{ V}$
- (3) $V_{DS} = 45 \text{ V}$
- (4) $V_{DS} = 40 \text{ V}$ (5) $V_{DS} = 35 \text{ V}$
- (6) $V_{DS} = 30 \text{ V}$
- Fig 10. Drain efficiency as a function of output power; typical values

8. Package outline

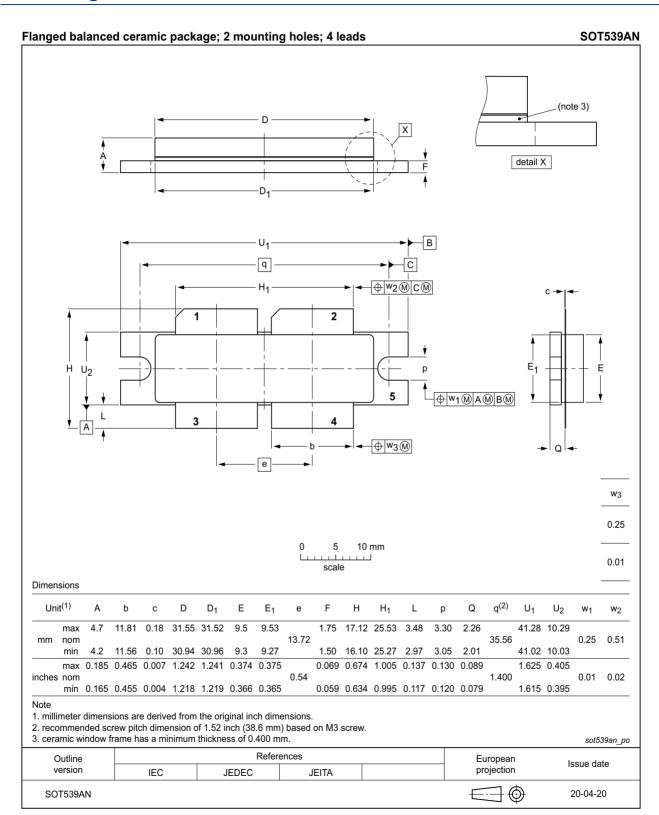


Fig 11. Package outline SOT539AN

ART1K6FH_1K6FHS_1K6FHG

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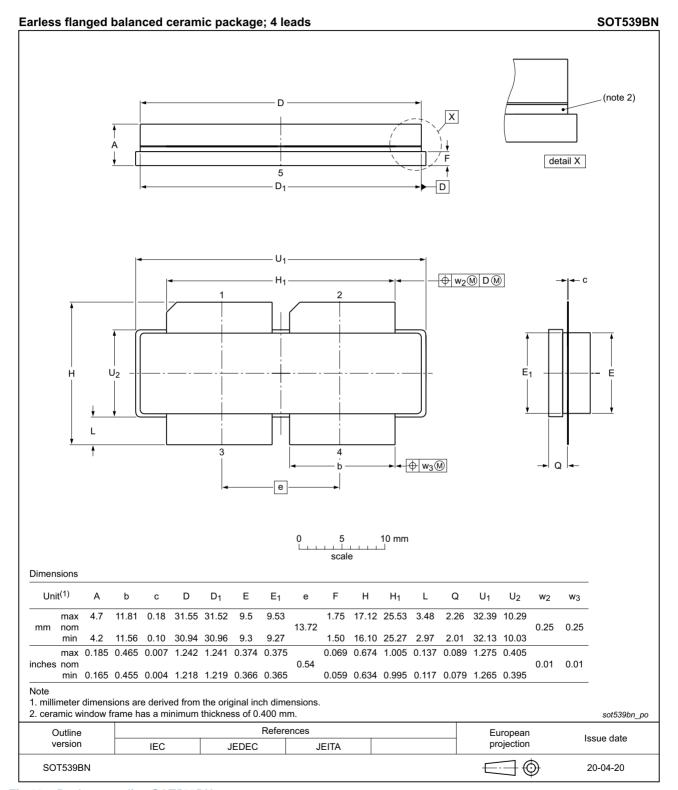


Fig 12. Package outline SOT539BN

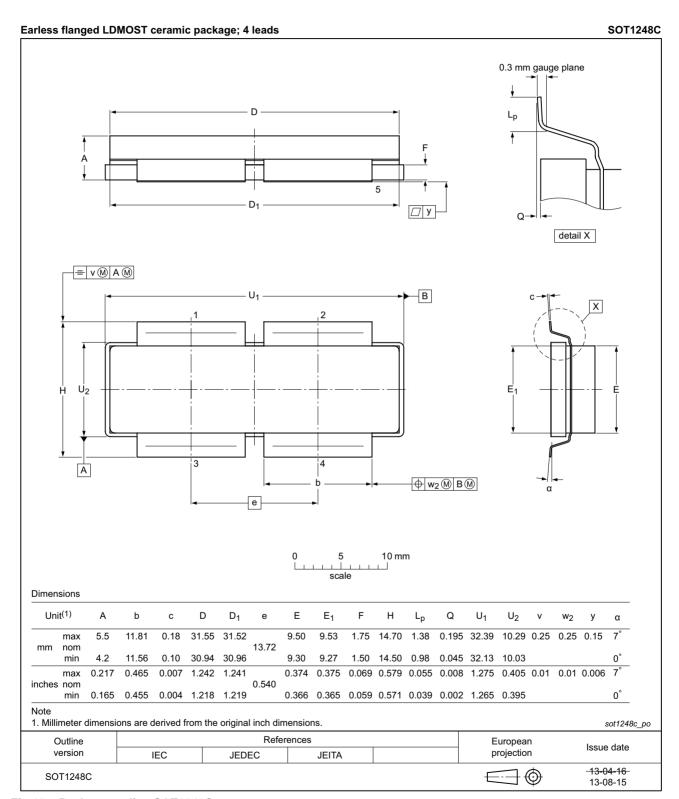


Fig 13. Package outline SOT1248C

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 11. ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2A [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 [2]

- [1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V.
- [2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V.

10. Abbreviations

Table 12. Abbreviations

Acronym	Description
CW	Continuous Wave
ESD	ElectroStatic Discharge
FM	Frequency Modulation
ISM	Industrial, Scientific and Medical
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MRI	Magnetic Resonance Imaging
MTF	Median Time to Failure
RoHS	Restriction of Hazardous Substances
SMD	Surface Mounted Device
UHF	Ultra High Frequency
VHF	Very High Frequency
VSWR	Voltage Standing Wave Ratio

11. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
ART1K6FH_1K6FHS_1K6FHG v.3	20220708	Product data sheet	-	ART1K6FH_1K6FHS_1K6FHG v.2
Modifications:	<u>Table 4 on page 3</u> : changed values gate-source voltage			
	<u>Table 6 on page 5</u> : changed value gate-source voltage			
ART1K6FH_1K6FHS_1K6FHG v.2	20220322	Product data sheet	-	ART1K6FH v.1
ART1K6FH v.1	20200925	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
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